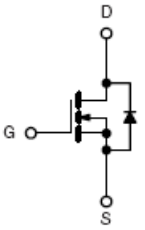
迈拓电子
MAITUO ELECTRONIC

MT2302T **Plastic-Encapsulate MOSFETS**

N-Channel 20-V(D-S) MOSFET



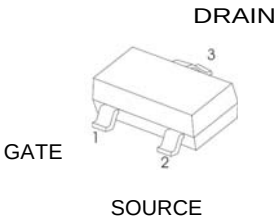
FEATURE

TrenchFET Power MOSFET

APPLICATIONS

Load Switch for Portable Devices

DC/DC Converter



MARKING: 2302

SOT-523

Maximum ratings (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±8	
Continuous Drain Current	I_D	2.1	A
Continuous Source-Drain Current(Diode Conduction)	I_S	0.6	
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient (t≤5s)	$R_{\theta JA}$	357	℃/W
Operating Junction	T_J	150	℃
Storage Temperature	T_{STG}	-55 ~+150	

Electrical characteristics (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =10μA	20			V
Gate-threshold voltage	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D = 250uA	0.50	0.65	1.0	
Gate-body leakage	I_{GSS}	V_{DS} =0V, V_{GS} =±8V			±100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} =20V, V_{GS} =0V			1	μA
Drain-source on-resistance[a]	$r_{DS(on)}$	V_{GS} =4.5V, I_D =2.0A		0.055	0.080	Ω
		V_{GS} =2.5V, I_D =1.8A		0.078	0.125	
Forward transconductance[a]	g_{fs}	V_{DS} =5V, I_D =1.6A		8		S
Diode forward voltage	V_{SD}	I_S=0.94A,V_{GS}=0V		0.76	1.2	V
Dynamic						
Total gate charge	Q_g	V_{DS} =10V,V_{GS} =4.5V,I_D =3.6A		4.0	10	nC
Gate-source charge	Q_{gs}			0.65		
Gate-drain charge	Q_{gd}			1.5		
Input capacitance [b]	C_{iss}	V_{DS} =10V,V_{GS} =0V,f=1MHz		300		pF
Output capacitance [b]	C_{oss}			120		
Reverse transfer capacitance[b]	C_{rss}			80		
Switching[b]						
Turn-on delay time	$t_{d(on)}$	V_{DD}=10V, R_L=5.5Ω, I_D ≈3.6A, V_{GEN}=4.5V,Rg=6Ω		7	15	ns
Rise time	t_r			55	80	
Turn-off delay time	$t_{d(off)}$			16	60	
Fall time	t_f			10	25	

Notes :

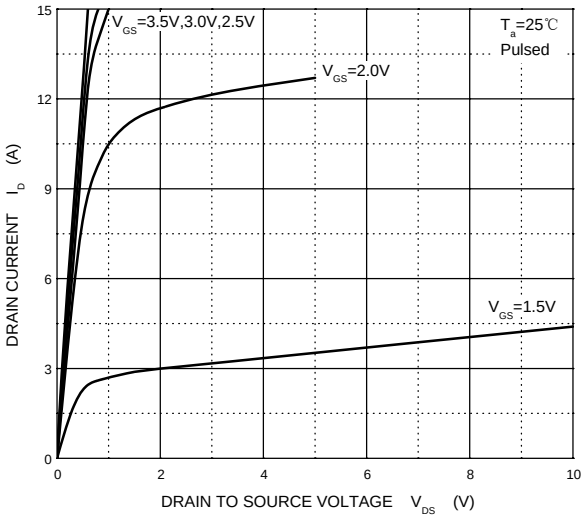
a. Pulse Test : Pulse width≤300μs, duty cycle ≤2%.

b. These parameters have no way to verify.

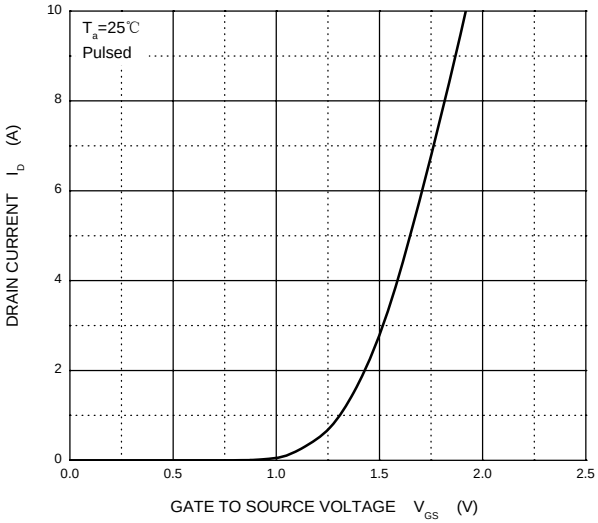
迈拓电子
MAITUO ELECTRONIC

Typical Characteristics

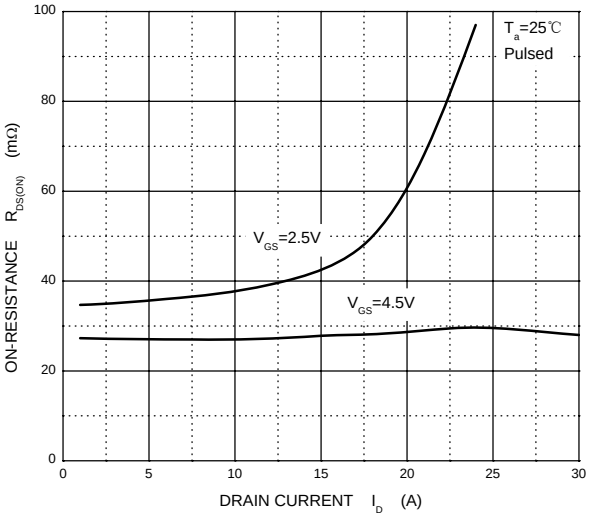
Output Characteristics



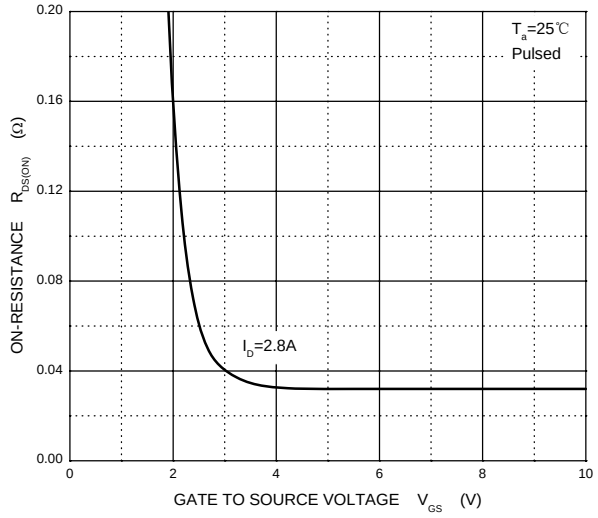
Transfer Characteristics



$R_{DS(ON)}$ — I_D

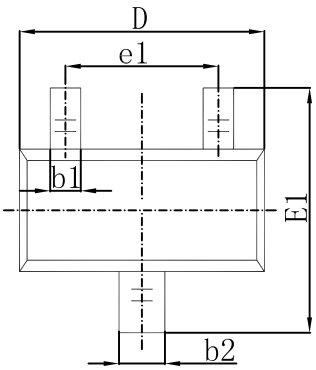


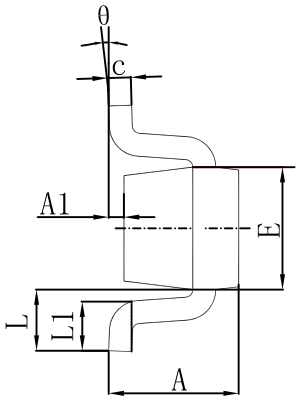
$R_{DS(ON)}$ — V_{GS}

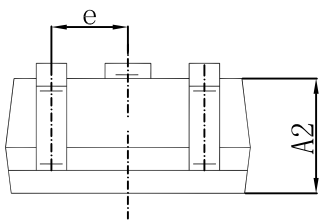


迈拓电子
MAITUO ELECTRONIC

SOT-523 Package Outline Dimensions

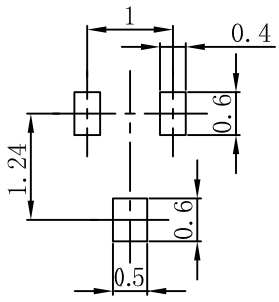






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.